A model of transport nonuniversality in thick- Im resistors

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We propose a model of transport in thick- Im resistors which naturally explains the observed nonuniversal values of the conductance exponent t extracted in the vicinity of the percolation transition. E sential ingredients of the model are the segregated microstructure typical of thick- Im resistors and tunneling between the conducting grains. Nonuniversality sets in as consequence of wide distribution of interparticle tunneling distances.

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Thick- In resistors (TFR s) are glass-conductor composites based on RuO₂ (but also $Bi_2Ru_2O_7$, $Pb_2Ru_2O_6$, and IrO₂) grains mixed and red with glass powders.¹ Besides the widespread use of TFRs in pressure and force sensor applications,² their transport properties are of great interest also for basic research. The percolating nature of transport in TFRs has been reported since long tim e and now it is welldocum ented.^{3{9} As shown in Fig.1 where we reports a selection of previously published data on di erent TFRs,^{5{8} the conducting phase concentration x dependence of the conductance G of TFRs follows a percolating-like power-law equation of the form :

$$G = G_0 (x \quad x_c)^{\mathsf{T}}; \tag{1}$$

where G_0 is a prefactor, x_c is the critical concentration below which G vanishes and t is the transport critical exponent.^{10;11} The values of G_0 , x_c , and t which best t the experim ental data are reported in the inset of Fig.1.

A coording to the standard theory of transport in isotropic percolating system s_r^{11} G $_0$ and x_c depend on m icroscopic details such as the m icrostructure and the m ean value of the junction resistances connecting two neighbouring conducting sites, while, unless the m icroscopic resistances have a diverging distribution function (see below), the critical exponent t is universal, i. e., it depends only upon the lattice dimensionality D . For D = 3, random resistor network calculations predict t = t_0 $^\prime$ 2:0, 12 in agreement with various granular metal system $s_r^{13;14}$ or other disordered compounds. 15

As it is clear from Fig.1, TFRs have values of tranging from its universal limit t ' 2:0 (lled squares, Ref. 5) up to very high values like t 5:0 (lled diam onds, Ref.7) or even higher.³ D espite of their clear percolating

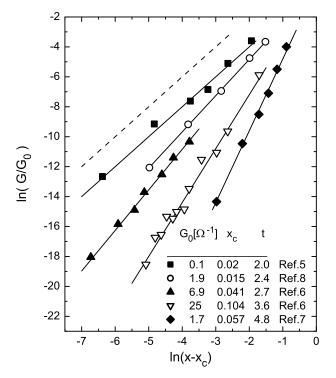


FIG.1. M easured conductances on di erent RuO_2 (Refs. 6, 8) and $Bi_2Ru_2O_7$ (Refs. 5, 7) TFRs. Solid lines are ts to Eq.(1) with tting values reported in the inset. dashed line denotes a power-law with exponent t = 2.

behavior, TFRs do not full therefore the hypothesis of universality common tom any system s and instead belong to a di erent, quite vast, class of materials which display nonuniversal transport behavior, that is a regime where the transport exponent t depends on microscopic details (microstructure etc.). Typical examples of nonuniversal system s are carbon-black (polymer composites,²⁰ and materials constituted by insulating regions embedded in a continuous conducting phase.^{14,16}

D espite that TFRs have been historically among the rst materials for which transport nonuniversality has been reported,³ the microscopic origin of their universality breakdown has not been specifically addressed so far. In this letter we show that the cross-over between universality and nonuniversality reported in Fig.1 can be explained within a single model whose basic features are the peculiar microstructure of TFRs and the tunneling processes between conducting grains.

Before describing our model for TFRs, let us rst recall the mathematical requisites for universality breakdown in random resistor networks. Consider a regular lattice of sites and assign to each neighbouring couple of sites a bond which has nite conductance g with probability p and zero conductance with probability 1 p. The resulting conductance distribution function is then:

$$(g) = ph(g) + (1 p) (g);$$
 (2)

where (g) is the D irac delta-function and h(g) is the distribution function of the nitebond conductances. For well behaved distribution functions h(g), conductivity is universal and follow sEq.(1) with $t = t_0$. Instead, as rst shown by K ogut and Straley,¹⁷ if h(g) has a power law divergence for small g of the form :

$$\lim_{q \downarrow 0} h(g) / g ; \qquad (3)$$

and is larger than a critical value _c, then transport is no longer universal. Renorm alization group analysis predicts in fact that

$$t = \begin{array}{ccc} t_0 & \text{if} & +1 = (1 &) < t_0 \\ & +1 = (1 &) & \text{if} & +1 = (1 &) > t_0 \end{array}; \quad (4)$$

where ' 0.88 is the correlation-length exponent for a three dimensional lattice.¹⁸ By using t_0 ' 2.0 we obtain therefore $_c$ ' 0.107. Equations (3) and (4) have been shown to arise from a system of insulating spheres em – bedded in a continuous conducting material (sw iss-cheese model),¹⁹ and from a tunneling-percolation model with highly uctuating tunneling distances.²⁰ Here we show that Eq.(3) [and consequently Eq.(4)] arises naturally from a simple representation of TFRs in terms of their m icrostructure and elemental transport processes.

Let us start by considering the highly nonhom ogeneousm icrostructure typical of TFRs. These system s are constituted by a mixture of large glassy particles (typically with size L of order 1-3 m) and sm all conducting grains of size varying between 10 nm up to 200 nm . In this situation, the sm all m etallic grains tend to occupy the narrow regions between the much larger insulating zones leading to a lam entary distribution of the conducting phase. A classical model to describe such a segregation e ect was proposed already in the 1970's by Pike.³ Thism odel treats the glassy particles as cubes of size L whose edges are occupied by chains of adjacent m etallic spheres of diam eter . Such chains de ne channels (bonds) which form a cubic lattice spanning the whole sample. Let us assume for the moment that a bond has probability p of being occupied by a xed number n + 1 of spheres and probability 1 p of being em pty. To each couple of adjacent spheres we assign an inter-sphere conductance i (i = 1;;n). A random resistor network can be therefore de ned as in Eq.(2) where h_n (g) is the distribution function of the total channel conductance g of n conductances i in series:

$$g^{-1} = \frac{X^{n}}{\sum_{i=1}^{i} \frac{1}{i}}$$
(5)

The high values of piezoresistance (i.e., the strain sensitivity of transport) typical of TFRs,¹ and the low tem – perature dependence of transport strongly indicate that the main contribution to the overall resistance stems from tunneling processes between neighbouring m etallic grains. Hence, if the centers of two neighbouring m etallic spheres are separated by a distance r, then the intergrain tunneling conductance is approximatively of the form:

$$= (r) _{0}e^{2(r)} = ; \qquad (6)$$

where p_is a constant which we set equal to the unity,

/ 1 = V is the tunneling factor and V is the intergrain barrier potential. Let us make the quite general assumption that the centers of the spheres are set random ly along the channel, so that the distances r change according to the distribution function P (r) for a set of im penetrable spheres arranged random ly in a quasi one dimensional channel. By following Ref.²¹, P (r) can be calculated exactly and its explicit expression is:

P (r) =
$$\frac{1}{a_n} e^{(r) = (a_n)}$$
 (r) (7)

where $a_n = (1 + L = n) = 2$ is the mean inter-sphere distance and is the step function. By combining Eq.(6) with Eq.(7) the distribution f () of the inter-sphere conductances is then:

$$f() = dr P(r) [(r)] = (1 _{n}) ^{n}; (8)$$

where

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$$_{n} = 1 \quad \frac{=2}{a_{n}}$$
: (9)

To obtain the distribution function h_n (g) of the occupied channels, we rst note that Eq.(5) in plyies that g

is dominated by the minimum inter-sphere conductance m_{in} among the set of n conductances in series. Hence the small-g limit of h_n (g) is just the distribution function f of m_{in} :

which, from Eq.(8) and by setting $g'_{m in}$, leads to:

0

$$\lim_{n \to \infty} h_n (g) ' n (1_n) g^n :$$
 (11)

The conducting bond distribution function behaves therefore as Eq.(3) so that for $_n > _c$ ' 0:107 transport universality breaks down and t > t₀. For L = 1 m, = 10 nm, and = 1 nm this is achieved already for n < 90, i. e., slightly less then the maximum number L = = 100 of spheres which can be accommodated inside a channel.

O ur m odel of universality breakdown in TFRs can be readily generalized to describe m ore realistic situations. For example, the number n of spheres inside the occupied channels can vary according to a given distribution. It is also straightforward to rewrite Eq.(7) in order to describe cases in which the diameter of the spheres is not xed,²² or to let the size of the insulating grains to change by assigning a distribution function for L. It is then possible to have di erent scenarios and, m ore im portantly, to obtain a crossover from transport universality (t = t₀) to nonuniversality (t > t₀) within the same fram ew ork. This rem inds the experimental situation reported for TFRs and sum marized in Fig.1.

Let us now comment on the capability of other existing theories to describe transport universality breakdown in TFRs. At a rst glance, the swiss-cheese model of Ref. 19 is a natural candidate since the large values of L = typical of m any TFRs m ay lead to an e ective continuous conducting phase lling the voids between the large glassy grains. How ever, there are examples in which nonuniversality has been reported for TFRs with L= 5 10^5 , a value probably too sm all to only of order be compatible with the swiss-cheese picture. Even more problem atic are the cases for which $t = t_0 / 2.0$ has been measured for TFRs with L= 100 (see for exam ple Fig.1), while the swiss-cheese model would have predicted $t > t_0$. Regarding instead the model proposed by Balberg,²⁰ for which transport is dom inated by random tunneling processes in a percolating network, it is important to point out that it was de ned by using a phenom enological distribution function for the nearestneighbour particle distances very sim ilar to our Eq.(7). Balberg argured that such form of P (r) is a reasonable compromise between the distribution function of spheres random ly placed in three dimensions,²¹ and the e ect of interactions between the conducting and insulating phases. Instead we have shown that Eq.(7), and consequently the power-law divergence of h (g), is a straightforward outcome of the quasi one-dimensional geom etry of the conducting channels in the segregation m odel of TFRs. Despite that our m odel has been form ulated speci cally for TRFs, nevertheless it could be applied also to other segregated disordered com pounds for which tunneling is the main mechanism of transport and nonuniversality has been reported.¹⁶

In conclusion, we have proposed a simple tunnelingpercolation model capable of describing the observed transport universality breakdown in TFRs. E sential ingredients of the theory are the segregated structure, modelled by quasi-one dimensional channels occupied random ly by the conducting particles, and intergrain tunneling taking place within the channels.

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